

HL6501MG

Visible High Power Laser Diode

ODE2031-00 (M) Rev.0 Aug. 01, 2008

Description

The HL6501MG is a 0.65 μ m band AlGaInP laser diode (LD) with a multi-quantum well (MQW) structure. It is suitable as a light source for large capacity optical disc memories and various other types of optical equipment. Hermetic sealing of the small package (ϕ 5.6 mm) assures high reliability.

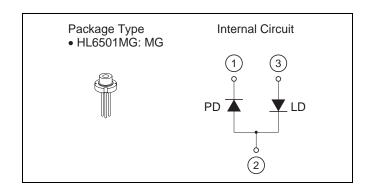
Features

High output power: 35 mW (CW)
Visible light output: \(\lambda p = 658 \) nm Typ

• Small package: \$\phi\$ 5.6 mm

• Low astigmatism: $6 \mu m \text{ Typ } (P_0 = 5 \text{ mW})$

• Single longitudinal mode



Absolute Maximum Ratings

 $(T_C = 25^{\circ}C)$

| Item | Symbol | Ratings | Unit |
|----------------------------|-----------------------|------------|------|
| Optical output power | Po | 35 | mW |
| Pulse optical output power | P _{O(pulse)} | 50 * | mW |
| LD reverse voltage | $V_{R(LD)}$ | 2 | V |
| PD reverse voltage | V _{R(PD)} | 30 | V |
| Operating temperature | Topr | -10 to +60 | °C |
| Storage temperature | Tstg | -40 to +85 | °C |

Note: Pulse condition: Pulse width = 100 ns, duty = 50%

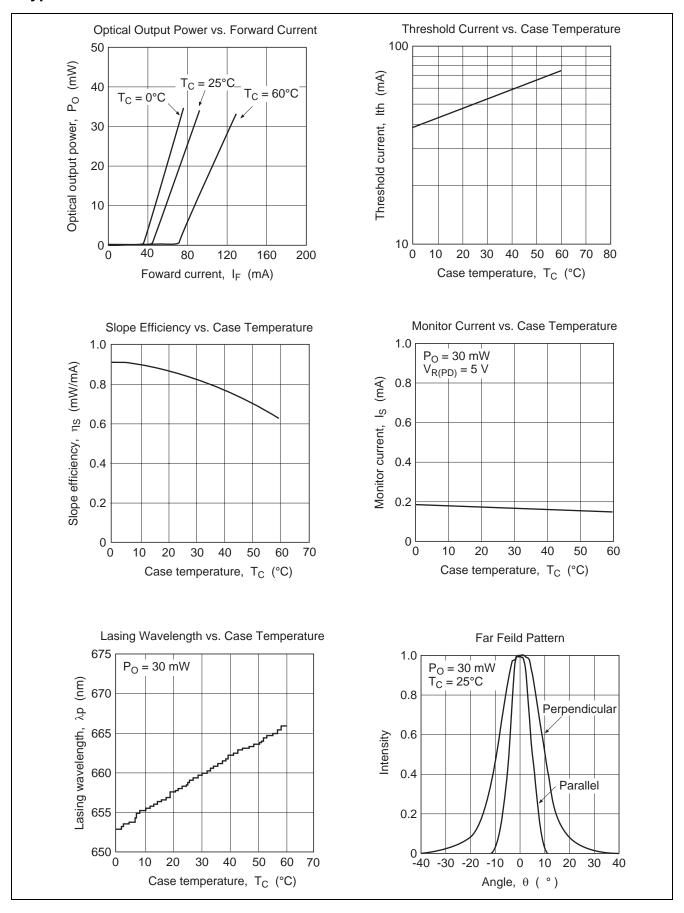
Optical and Electrical Characteristics

 $(T_C = 25^{\circ}C)$

| Item | Symbol | Min | Тур | Max | Unit | Test Conditions |
|---|-----------------|------|------|------|-------|---|
| Threshold current | Ith | 30 | 45 | 70 | mA | _ |
| Operating voltage | V _{OP} | 2.1 | 2.6 | 3.0 | V | P _O = 30 mW |
| Slope efficiency | ηѕ | 0.5 | 0.75 | 1.0 | mW/mA | 18 (mW) / (I _(24mW) – I _(6mW)) |
| Beam divergence parallel to the junction | θ// | 7 | 8.5 | 10.5 | 0 | P _O = 30 mW |
| Beam divergence perpendicular to the junction | θΤ | 18 | 22 | 26 | 0 | P _O = 30 mW |
| Astigmatism | As | _ | 6 | _ | μm | $P_0 = 5 \text{ mW}, NA = 0.55$ |
| Lasing wavelength | λр | 645 | 658 | 665 | nm | P _O = 30 mW |
| Monitor current | I _S | 0.05 | 0.2 | 1.5 | mA | $P_{O} = 30 \text{ mW}, V_{R(PD)} = 5 \text{ V}$ |



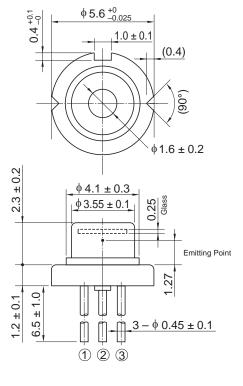
Typical Characteristic Curves

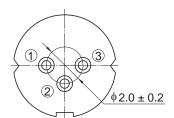


Package Dimensions

As of July, 2002 Unit: mm







| OPJ Code | LD/MG |
|------------------------|-------|
| | |
| JEDEC | — |
| JEITA | _ |
| Mass (reference value) | 0.3 g |

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- 2. This product contains gallium arsenide (GaAs), which may seriously endanger your health even at very low doses. Please avoid treatment which may create GaAs powder or gas, such as disassembly or performing chemical experiments, when you handle the product.
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Sales Offices



Opnext Japan, Inc.

Takagi Bldg., 3F, 1-3-9, Iwamoto-cho, Chiyoda-ku, Tokyo 101-0032, Japan Tel: (03) 3865-5591

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